## NSN 5962-01-277-8716

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View Online at https://aerobasegroup.com/nsn/5962-01-277-8716

Body Length:
Between 1.030 inches and 1.200 inches
Body Width:
Between 0.250 inches and 0.320 inches
Body Height:
0.230 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
5865-01-262-7031 communication p
Features Provided:
Hermetically sealed and burn in and high speed and static operation and low power and 3-state output
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
20 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
35.00 nanoseconds propagation delay time, low to high level output and 35.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Ram
Memory Capacity:
Unknown
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
22 printed circuit
Shelf Life:

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N/a

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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